



High Power Laser Diode

Overview

DL-6140-201 is high power (50mW) 785nm laser diode. DL-6140-201 is suitable for CD-R.

Features

•High power : 50 mW at 60°C

•Index guided type

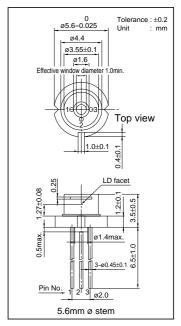
•Small package : 5.6 mmØ

•PIN photodiode built-in for light output monitor

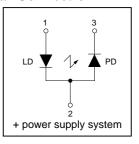
Absolute Maximum Ratings at Tc=25°C

Parameter		Symbol	Ratings	Unit	
Light Output		Po	55	mW	
Reverse Voltage	Laser PIN	VR	2 30	V	
Operating Temperature		Topr	-10 to +60	°C	
Storage Temperature		Tstg	-40 to +85	°C	

Package Dimensions



Electrical Connection



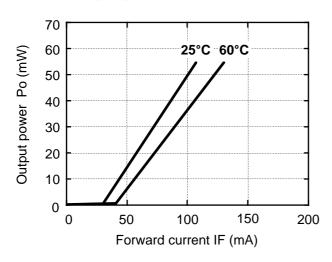
Electrical and Optical Characteristics at Tc=25°C

Para	meter	Symbol	Condition	Min.	Тур.	Max.	Unit
Threshol	d Current	Ith	CW	20	30	50	mA
Operating	g Current	Iop	Po=50mW	-	100	140	mA
Operating	g Voltage	Vop	Po=50mW	_	2.0	2.5	V
Lasing W	avelength	λp	Po=50mW	775	785	795	nm
Beam **)	Perpendicular	$\theta \perp$	Po=50mW	18	22	26	deg.
Divergence	Parallel	θ //	Po=50mW	7.0	8.0	9.5	deg.
Off Axis	Perpendicular	$\Delta heta \perp$	_	-	-	±3	deg.
Angle	Parallel	$\Delta heta$ //	_	_	-	±3	deg.
Differentia	Efficiency	dPo/dIop	-	0.40	0.70	0.90	mW/mA
Monitoring C	utput Current	Im	Po=50mW	0.05	0.20	0.50	mA
Astigr	natism	As	Po=50mW	-	10	-	μm

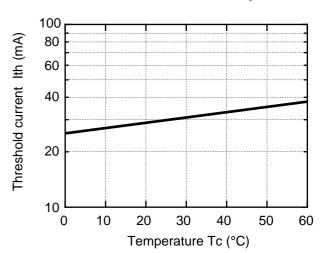
*) Full angle at half maximum note: The above product specifications are subject to change without notice.

Characteristics

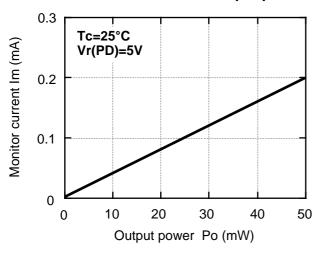
Output power vs. Forward current



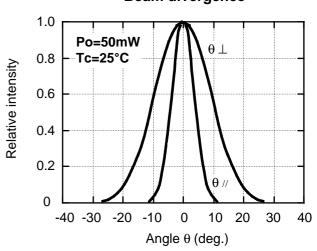
Threshold current vs. Temperature



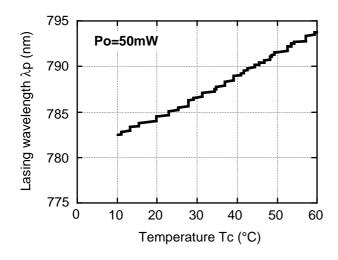
Monitor current vs. Output power



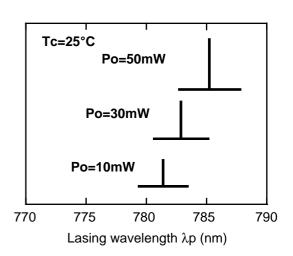
Beam divergence



Lasing wavelength vs. Temperature



Output power vs. Lasing wavelength



Relative intensity



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Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

Manufactured by; Tottori SANYO Electric Co., Ltd.

Electronics Device Bussiness Headquaters LED Division 5-318, Tachikawa-cho, Tottori City, 680-8634 Japan TEL: +81-857-21-2137 FAX: +81-857-21-2161